

# NPN Epitaxial Silicon Transistor

## SS8050

### Features

- 2 W Output Amplifier of Portable Radios in Class B Push–Pull Operation
- Complementary to SS8550
- Collector Current:  $I_C = 1.5$  A
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector–Base Voltage	$V_{CBO}$	40	V
Collector–Emitter Voltage	$V_{CEO}$	25	V
Emitter–Base Voltage	$V_{EBO}$	6	V
Collector Current	$I_C$	1.5	A
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	–65 to 150	$^\circ\text{C}$

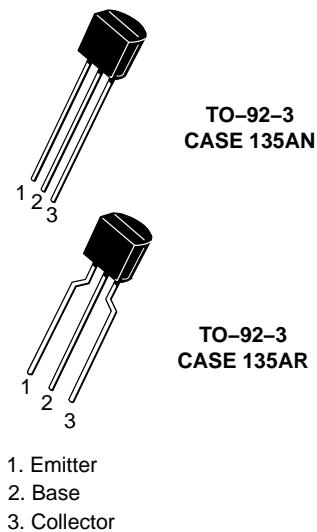
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS (Note 1)

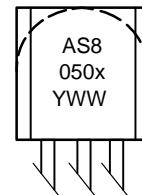
( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Value	Unit
Power Dissipation	$P_D$	1	W
Derate Above $25^\circ\text{C}$		8	$\text{mW}/^\circ\text{C}$
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$

1. PCB size: FR–4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.



### MARKING DIAGRAM



S8050x = Specific Device Code

Line 1: A = Assembly Location

Line 2: x = B, C or D

Line 3: Y = Year

WW= Work Week

### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

# SS8050

## ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV <sub>CBO</sub>	Collector–Base Breakdown Voltage	I <sub>C</sub> = 100 µA, I <sub>E</sub> = 0	40			V
BV <sub>CEO</sub>	Collector–Emitter Breakdown Voltage	I <sub>C</sub> = 2 mA, I <sub>B</sub> = 0	25			V
BV <sub>EBO</sub>	Emitter–Base Breakdown Voltage	I <sub>E</sub> = 100 µA, I <sub>C</sub> = 0	6			V
I <sub>CBO</sub>	Collector Cut–Off Current	V <sub>CB</sub> = 35 V, I <sub>E</sub> = 0			100	nA
I <sub>EBO</sub>	Emitter Cut–Off Current	V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0			100	nA
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 5 mA	45			
		V <sub>CE</sub> = 1 V, I <sub>C</sub> = 100 mA	85		300	
		V <sub>CE</sub> = 1 V, I <sub>C</sub> = 800 mA	40			
V <sub>CE(sat)</sub>	Collector–Emitter Saturation Voltage	I <sub>C</sub> = 800 mA, I <sub>B</sub> = 80 mA			0.5	V
V <sub>BE(sat)</sub>	Base–Emitter Saturation Voltage	I <sub>C</sub> = 800 mA, I <sub>B</sub> = 80 mA			1.2	V
V <sub>BE(on)</sub>	Base–Emitter On Voltage	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 10 mA			1	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz		9.0		pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 50 mA	100			MHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## h<sub>FE</sub> CLASSIFICATION

Classification	B	C	D
h <sub>FE2</sub>	85 ~ 160	120 ~ 200	160 ~ 300

## ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping
SS8050BBU	S8050B	TO-92-3, case 135AN (Pb-Free)	10,000 Units/ Bulk Box
SS8050CBU	S8050C	TO-92-3, case 135AN (Pb-Free)	10,000 Units/ Bulk Box
SS8050CTA	S8050C	TO-92-3, case 135AR (Pb-Free)	2,000 Units/ Fan-Fold
SS8050DBU	S8050D	TO-92-3, case 135AN (Pb-Free)	10,000 Units/ Bulk Box
SS8050DTA	S8050D	TO-92-3, case 135AR (Pb-Free)	2,000 Units/ Fan-Fold

## TYPICAL PERFORMANCE CHARACTERISTICS

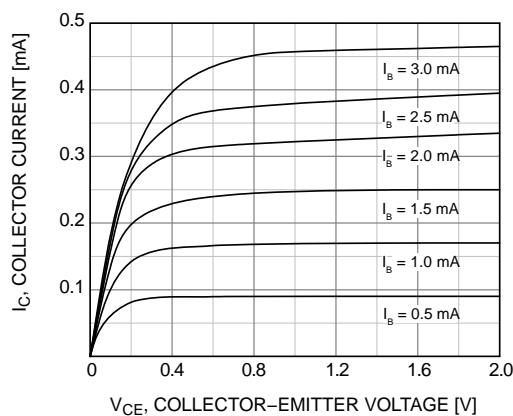


Figure 1. Static Characteristic

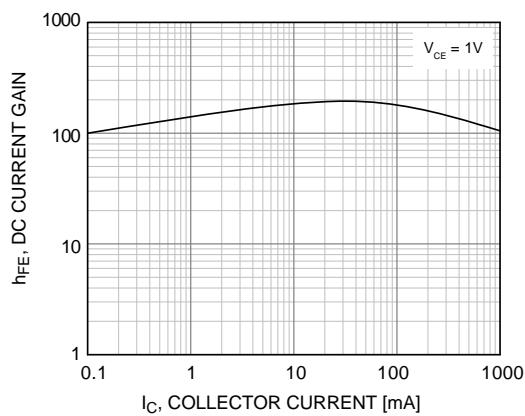


Figure 2. DC Current Gain

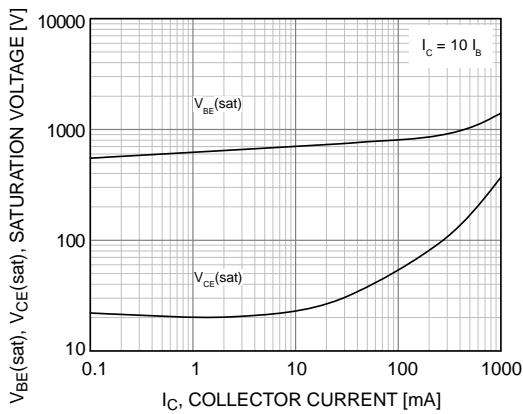


Figure 3. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

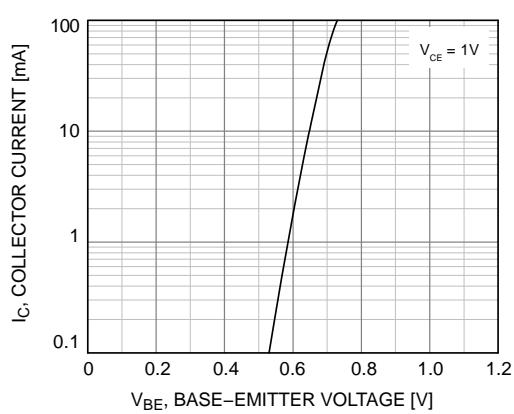


Figure 4. Base-Emitter On Voltage

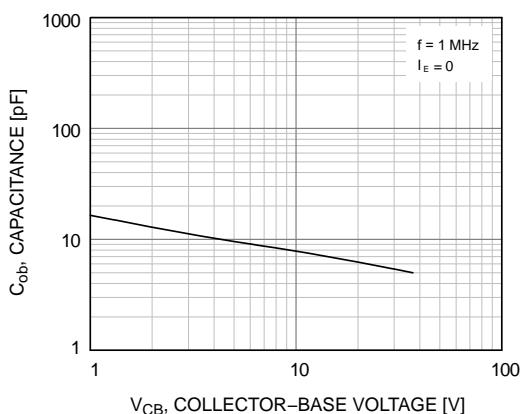


Figure 5. Collector Output Capacitance

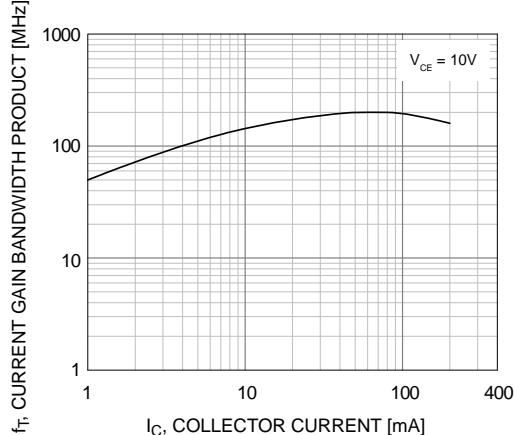
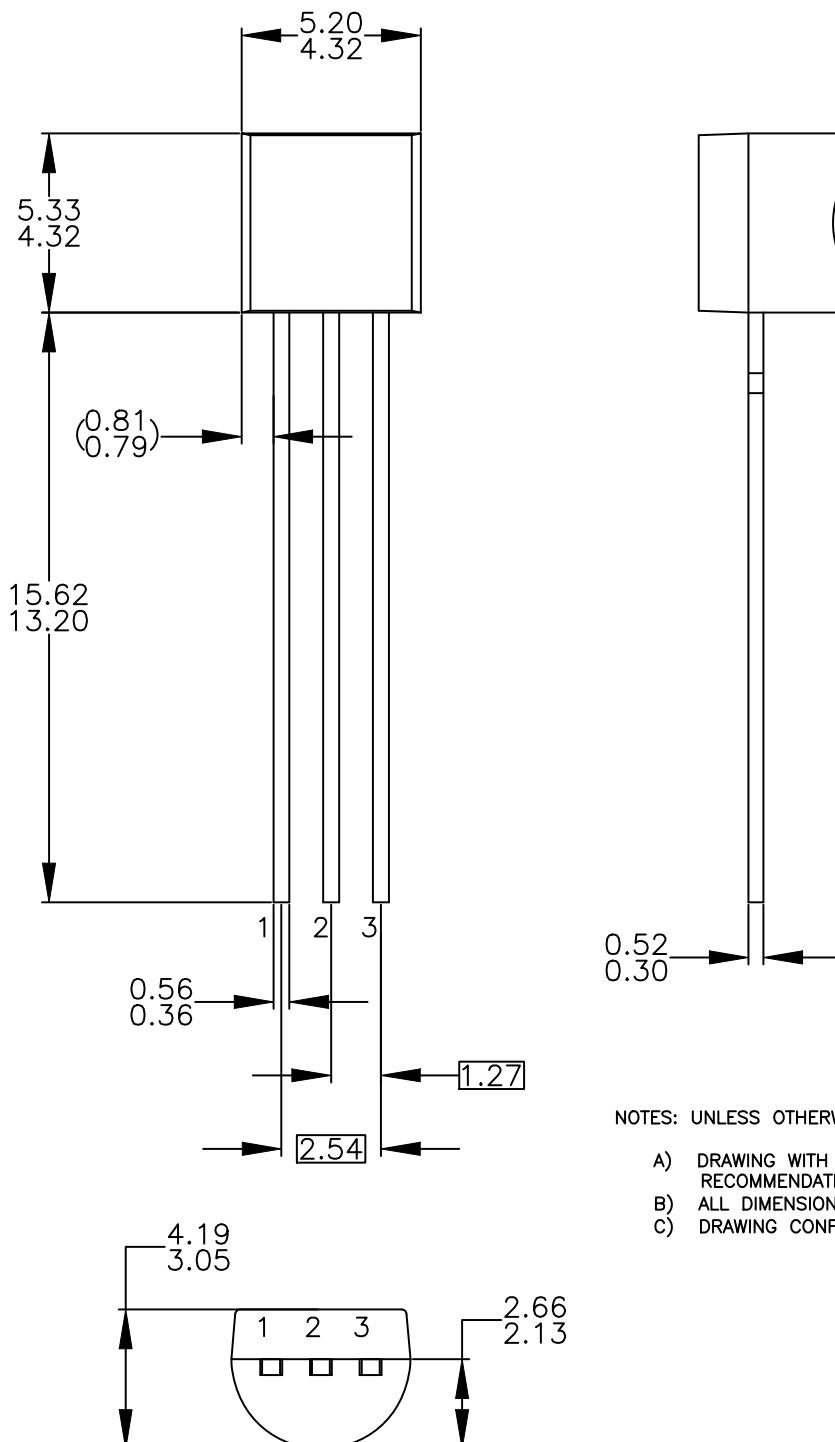


Figure 6. Current Gain Bandwidth Product

TO-92 3 4.825x4.76  
CASE 135AN  
ISSUE O

DATE 31 JUL 2016



## NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-2009.

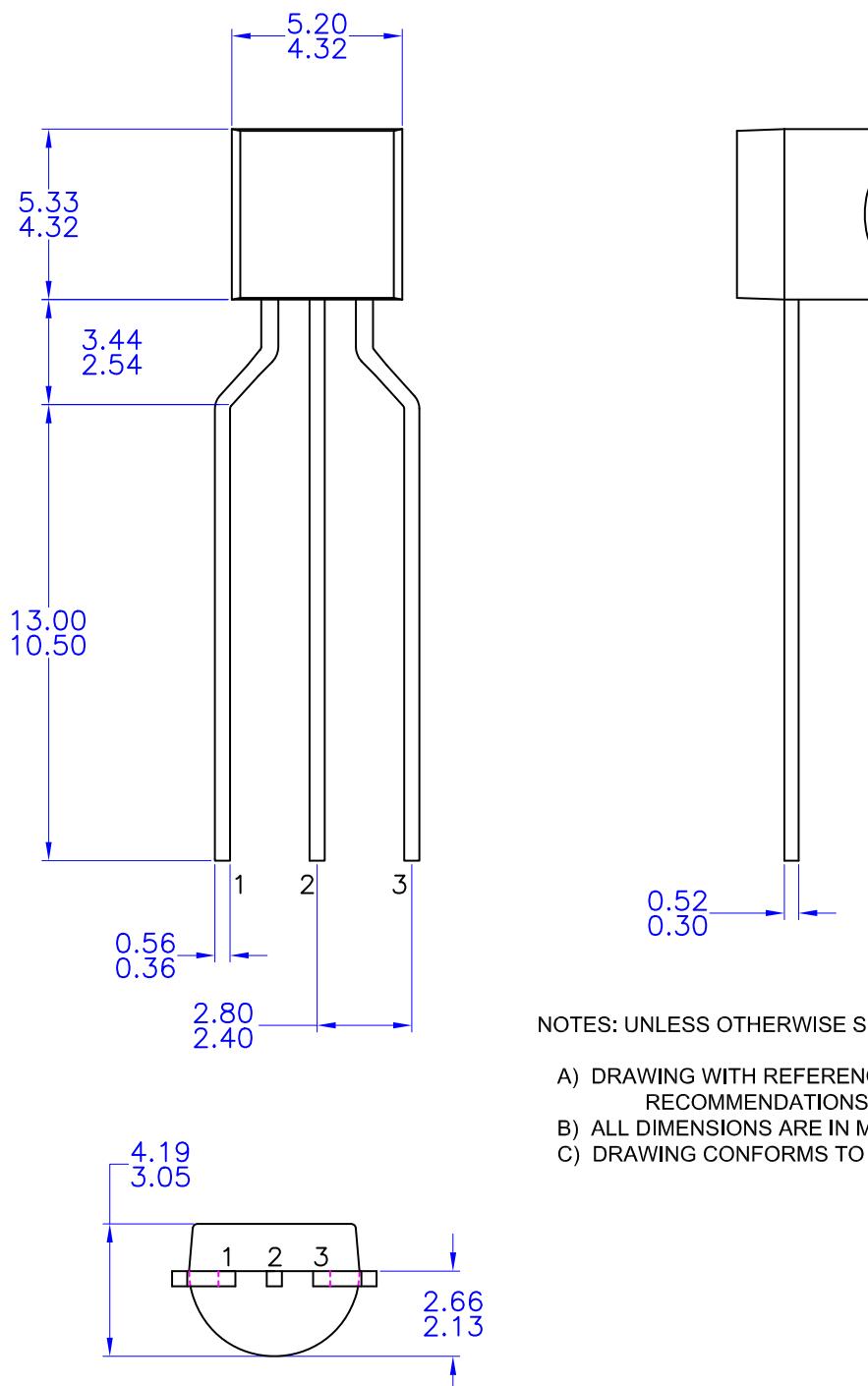
DOCUMENT NUMBER:	98AON13880G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TO-92 3 4.825X4.76	PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

## TO-92 3 4.83x4.76 LEADFORMED

CASE 135AR  
ISSUE O

DATE 30 SEP 2016



DOCUMENT NUMBER:	98AON13879G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	TO-92 3 4.83x4.76 LEADFORMED	PAGE 1 OF 1

onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

**onsemi**, **ONSEMI**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## ADDITIONAL INFORMATION

### TECHNICAL PUBLICATIONS:

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

### ONLINE SUPPORT: [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at  
[www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)

